NSN 5961-01-341-0054

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-341-0054 **Inclosure Material:** Ceramic **Overall Length:** 0.300 inches **Overall Diameter:** 0.104 inches **End Application:** Receiver-transmitter, rt-1476a/ arc-201 **Mounting Method:** Terminal **Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 25.0 breakdown voltage, dc **Power Rating Per Characteristic:** 250.0 milliwatts small-signal input power, common-collector absolute **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius ambient air **Precious Material And Location:** Terminal surface option gold **Test Data Document:** 80063-a3012733 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: A110a0